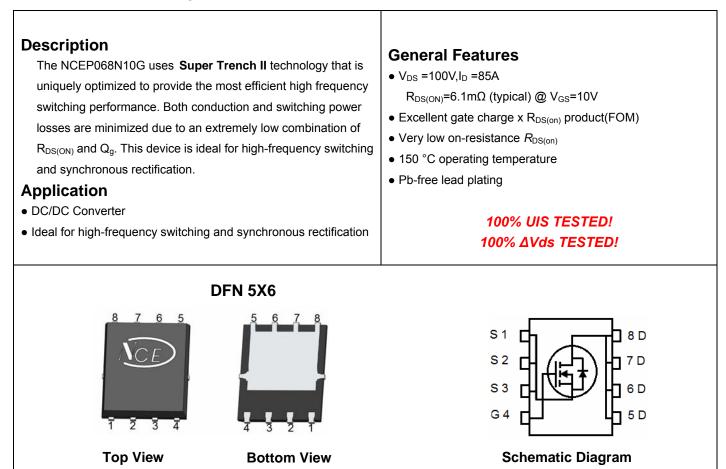


NCE N-Channel Super Trench II Power MOSFET



Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|-------------|----------------|-----------|------------|----------|
| P068N10G | NCEP068N10G | DFN5X6-8L | - | - | - |

Absolute Maximum Ratings (T_c=25℃ unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--|-----------------------|------------|------|
| Drain-Source Voltage | Vds | 100 | V |
| Gate-Source Voltage | V _{GS} | ±20 | V |
| Drain Current-Continuous | Ι _D | 85 | A |
| Drain Current-Continuous(T _C =100℃) | I _D (100℃) | 61 | A |
| Pulsed Drain Current | I _{DM} | 340 | A |
| Maximum Power Dissipation | PD | 105 | W |
| Derating factor | | 0.84 | W/℃ |
| Single pulse avalanche energy (Note 5) | E _{AS} | 320 | mJ |
| Operating Junction and Storage Temperature Range | T_{J},T_{STG} | -55 To 150 | °C |

Thermal Characteristic

| Thermal Resistance, Junction-to-Case ^(Note 2) | R _{θJC} | 1.2 | °C /W |] |
|--|------------------|-----|--------------|---|
|--|------------------|-----|--------------|---|



Electrical Characteristics (T_c=25 $^\circ\!\mathrm{C}$ unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|---|-----|------|------|------|
| Off Characteristics | | | • | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250µA | 100 | | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =100V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V_{GS} =±20V, V_{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | | | • | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 2 | 3.3 | 4 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =10V, I _D =40A | - | 6.1 | 6.8 | mΩ |
| Gate resistance | Rg | F=1.0MHz | | 1.3 | | Ω |
| Forward Transconductance | g fs | V _{DS} =5V,I _D =40A | | 60 | - | S |
| Dynamic Characteristics (Note4) | · · · | | • | | | |
| Input Capacitance | C _{lss} | V _{DS} =50V,V _{GS} =0V, | - | 3600 | - | PF |
| Output Capacitance | C _{oss} | | - | 335 | - | PF |
| Reverse Transfer Capacitance | C _{rss} | F=1.0MHz | - | 19.5 | - | PF |
| Switching Characteristics (Note 4) | | | • | | | |
| Turn-on Delay Time | t _{d(on)} | | - | 16 | - | nS |
| Turn-on Rise Time | tr | V _{DD} =50V,I _D =40A V _{GS} =10V,R _G =3Ω | - | 11 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | | - | 35 | - | nS |
| Turn-Off Fall Time | t _f | | - | 9 | - | nS |
| Total Gate Charge | Qg |)/ _===0)// ======= | - | 60 | - | nC |
| Gate-Source Charge | Q _{gs} | V_{DS} =50V,I _D =40A, | - | 20 | | nC |
| Gate-Drain Charge | Q _{gd} | V _{GS} =10V | - | 15 | | nC |
| Drain-Source Diode Characteristics | | | • | | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =40A | - | | 1.2 | V |
| Diode Forward Current (Note 2) | I _S | | - | - | 85 | Α |
| Reverse Recovery Time | t _{rr} | T_J = 25°C, I_F = 40A | - | 45 | - | nS |
| Reverse Recovery Charge | Qrr | di/dt = 100A/µs ^(Note3) | _ | 125 | - | nC |

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t \leq 10 sec.

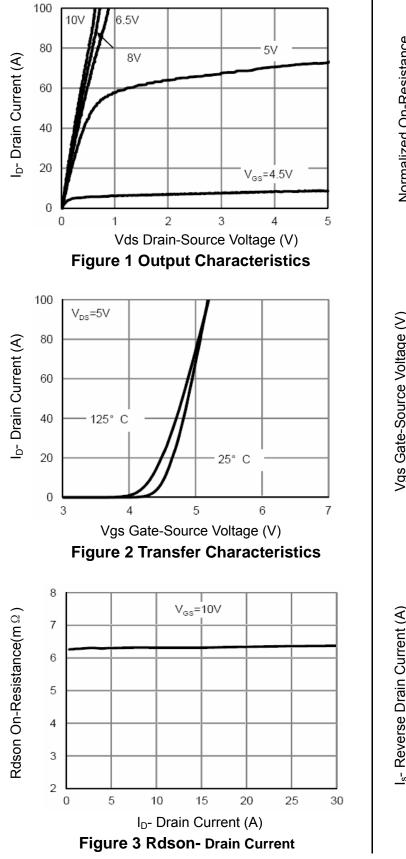
3. Pulse Test: Pulse Width ≤ 300 μ s, Duty Cycle ≤ 2%.

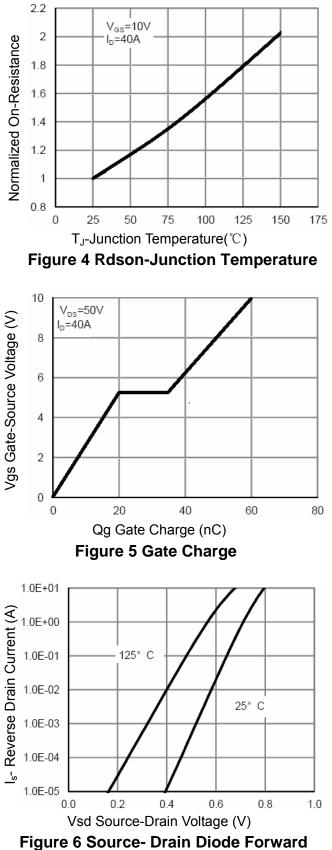
4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ C$,V_DD=50V,V_G=10V,L=0.5mH,Rg=25 Ω











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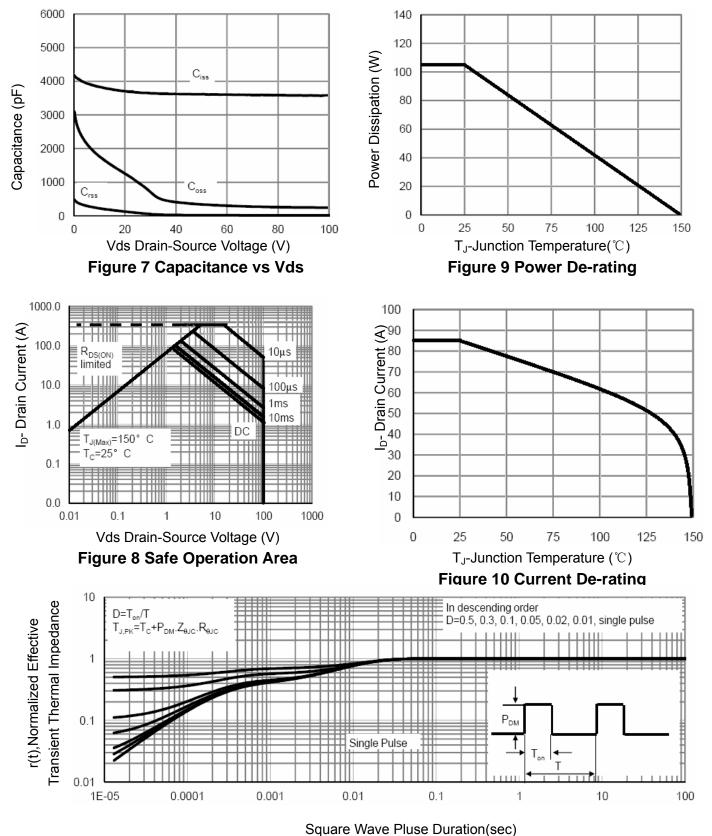
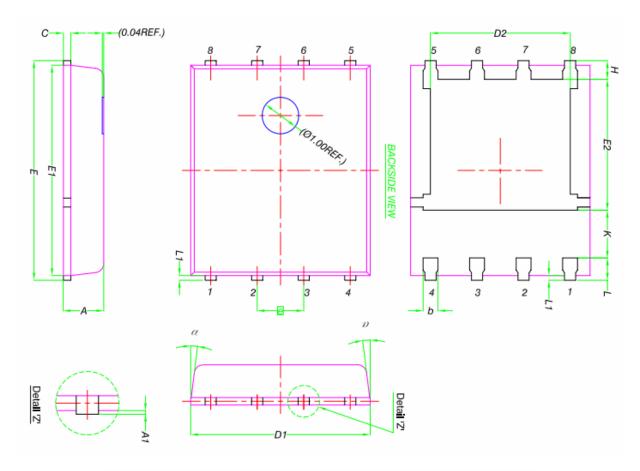


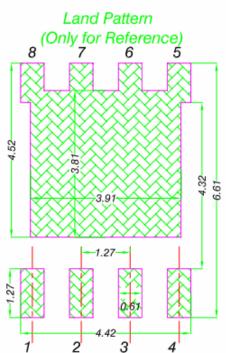
Figure 11 Normalized Maximum Transient Thermal Impedance



DFN5X6-8L Package Information



| | MILLIMETERS | | | |
|------|-------------|------|------|--|
| DIM. | MIN. | NOM. | MAX. | |
| А | 0.90 | 1.00 | 1.10 | |
| A1 | 0 | - | 0.05 | |
| b | 0.33 | 0.41 | 0.51 | |
| С | 0.20 | 0.25 | 0.30 | |
| D1 | 4.80 | 4.90 | 5.00 | |
| D2 | 3.61 | 3.81 | 3.96 | |
| E | 5.90 | 6.00 | 6.10 | |
| E1 | 5.70 | 5.75 | 5.80 | |
| E2 | 3.38 | 3.58 | 3.78 | |
| е | 1.27 BSC | | | |
| Н | 0.41 | 0.51 | 0.61 | |
| к | 1.10 | - | - | |
| L | 0.51 | 0.61 | 0.71 | |
| L1 | 0.06 | 0.13 | 0.20 | |
| α | 0° | - | 12° | |





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